<table>
<thead>
<tr>
<th>Title</th>
<th>Superconducting gap induced barrier enhancement in a BiFeO$_3$-based heterostructure</th>
</tr>
</thead>
<tbody>
<tr>
<td>Author(s)</td>
<td>Lu, C. L. Xing, Guozhong.; Xing, Guichuan.; Li, Mingjie.; Sie, Edbert Jarvis.; Wang, Dandan.; Sulistio, Arief.; Ye, Quan Lin.; Huan, Alfred Cheng Hon.; Wu, Tom.; Sum, Tze Chien.; Wang, Y.; You, L.; Zhou, X.; Xing, Guozhong; Chia, Elbert E. M.; Panagopoulos, Christos; Chen, L.; Liu, J. M.; Wang, J.; Wu, Tom; Peng, Haiyang</td>
</tr>
<tr>
<td>Date</td>
<td>2010</td>
</tr>
<tr>
<td>URL</td>
<td><a href="http://hdl.handle.net/10220/6836">http://hdl.handle.net/10220/6836</a></td>
</tr>
<tr>
<td>Rights</td>
<td>© 2010 American Institute of Physics. This paper was published in Applied Physics Letters and is made available as an electronic reprint (preprint) with permission of American Institute of Physics. The paper can be found at the following DOI: <a href="http://dx.doi.org/10.1063/1.3530446">http://dx.doi.org/10.1063/1.3530446</a>. One print or electronic copy may be made for personal use only. Systematic or multiple reproduction, distribution to multiple locations via electronic or other means, duplication of any material in this paper for a fee or for commercial purposes, or modification of the content of the paper is prohibited and is subject to penalties under law.</td>
</tr>
</tbody>
</table>
Multiferroics, materials simultaneously exhibiting multiple ferroic orders, have attracted significant attention due to the fundamental science and the tantalizing technological perspective.\textsuperscript{1-4} BiFeO\textsubscript{3} (BFO) is one of the most studied multiferroic materials because of its room temperature lead-free ferroelectricity ($T_C \sim 1103$ K) and antiferromagnetism ($T_N \sim 643$ K).\textsuperscript{5-7} At room temperature bulk BFO has a rhombohedral structure (point group R3c) with lattice parameters $a = 5.6343$ Å and $\alpha_r = 59.348^{\circ}$.\textsuperscript{8} Its spontaneous polarization ($P \sim 100$ $\mu$C/cm$^2$) along the pseudocubic (111) directions originates from the high stereochemical activity of Bi lone pairs,\textsuperscript{9} and could be the biggest switchable polarization among all perovskite ferroelectrics. The Fe$^{3+}$ spins are responsible for the G-type antiferromagnetic (AFM) ordering.\textsuperscript{4,9,10} Recently, reorientation of the easy M planes accompanying the P switching has been demonstrated by Zhao et al.\textsuperscript{11} using piezoresponse electron microscopy. Such a strong correlation between P and M, along with other exotic phenomena such as the electric field controlled exchange bias and the giant tunnel magnetoresistance, has inspired researchers to explore various BFO-based heterostructures.\textsuperscript{12-15}

In this work, we report the synthesis and characterization of a multiferroic/superconductor heterostructure composed of BFO and YBa$_2$Cu$_3$O$_{7-\delta}$ (YBCO) thin films. Interfacial couplings in such heterostructures can potentially present a wide range of emergent phenomena.\textsuperscript{16} Indeed, a variety of fascinating properties has been evidenced in YBCO-based junctions,\textsuperscript{17-21} rendering the BFO/YBCO heterostructure an excellent candidate in the search for novel properties in low dimensions.

The thin film heterostructures of BFO and YBCO were grown using pulsed laser deposition (PLD) on (001) SrTiO$_3$ (STO) single crystal substrates with TiO$_2$ surface termination. High quality YBCO thin film with good crystallinity and superconductivity was usually obtained at high substrate temperatures, e.g., $\sim 800$ °C,\textsuperscript{17,22} which may degrade BFO.\textsuperscript{23,24} Therefore, YBCO was deposited first, which also served as the bottom electrode in ferroelectric (FE) and transport studies. The YBCO bottom layer with a thickness of $\sim 80$ nm was grown in 150 mTorr oxygen at a substrate temperature of 780 °C, and then the BFO thin film was deposited at 80 mTorr and 670 °C. The topographic imaging and the piezoresponse force microscopy (PFM) measurements were carried out on an atomic force microscope (Asylum Research, USA, MFP-3D). Ferroelectric hysteresis loops were obtained using a precision ferroelectric tester (Radiant Technologies, USA). The temperature dependent dielectric property and the current-density-electric-field ($J$-$E$) curves were measured in a Janis Research cryogenic probe-station equipped with a Keithley 4200 semiconductor characterization system (Keithley, USA).

The x-ray diffraction (XRD) spectra for both the YBCO thin film and the BFO/YBCO heterostructure are shown in Figs. 1(a) and 1(b). The pure c-axis orientation indicates good crystallinity and epitaxial growth on the STO (001) substrate. No impurity phase was detected in the heterostructure, inding negligible interdiffusion or reaction at the interface. The out-of-plane lattice parameter of BFO in the heterostructure was found to be 3.99 Å, which is larger than that of the bulk counterpart (3.96 Å), indicating a biaxial compressive strain. This is in agreement with previous reports of BFO grown on STO substrates.\textsuperscript{4,5}

As shown in the topographic image in Fig. 1(c), the YBCO surface is covered by uniform nanoscale islands with a root mean square roughness ($R_{rms}$) of $\sim 2.3$ nm. The observed surface morphology has been reported previously for YBCO thin films due to the strain relaxation during deposition,\textsuperscript{22} which makes the subsequent deposition of high quality BFO a challenge.\textsuperscript{23-26} To probe the superconducting...
The out-of-plane PFM image is depicted in Fig. 2 shows grains larger than those on the single YBCO layer.

Fig. 1. (Color online) XRD patterns of (a) BFO/YBCO/STO and (b) YBCO/STO thin films. (c) 3 × 3 μm² topographic AFM image and (d) resistance vs temperature measured on the YBCO/STO thin film. The superconducting transition is indicated by a dashed line in (d).

After depositing BFO (~350 nm), the top surface of the heterostructure becomes rougher with an increased $R_{\text{rms}}$ of ~23 nm. The corresponding topographic image in Fig. 2(a) shows grains larger than those on the single YBCO layer. The out-of-plane PFM image is depicted in Fig. 2(b), which was recorded simultaneously with the topographic scan. Yellow (bright) and purple (dark) contrasts in Fig. 2(b) represent spontaneous polarization component pointing “up” and “down,” respectively. Most importantly, ferroelectricity was retained in the BFO/YBCO thin film heterostructure as evidenced in the FE hysteresis loops in Fig. 2(c) measured at different temperatures. The FE loops are squarelike with large remanent polarization $P_r$ of 65–70 μC/cm², which agrees well with previous reports. For comparison, BFO thin films were also grown on the conventionally used SrRuO$_3$ (SRO) buffer layers under the same growth conditions, and the corresponding FE loop [the solid line in Fig. 2(e)] is similar to the BFO/YBCO case. The quality of samples was further confirmed by the $E$-$P$ curves [Fig. 2(d)] measured at different temperatures showing the typical double-loop feature with two peaks appearing at the coercive field.

Accompanying the room temperature multiferroic properties, a well-known problem of BFO thin films is the large leakage current, leading to relatively high dielectric losses. The $J$-$E$ curves of the Pt/BFO/YBCO capacitorlike heterostructures were measured from room temperature down to 30 K. The FE domains were poled before each measurement. Figure 3 depicts typical transport data which contain some key information about this multiferroics/superconductor heterostructure.

Most recently, it has been demonstrated that the leakage current of Pt/BFO/SrRuO$_3$ (SRO) capacitor is interface-limited. Considering that YBCO is also an oxide electrode like SRO, we assumed that the same interface-limited mechanism dominates in the present Pt/BFO/YBCO heterostructures. Indeed, extensive fittings to the transport data suggest that the Schottky-like barrier model is most suitable to describe the conduction behavior observed in our samples. The current density across a Schottky barrier is

$$J = AT^2 \exp \left[ -\frac{\Phi}{k_B T} - \frac{1}{k_B T} \left( \frac{q^2 V}{4 \pi \varepsilon_0 K d} \right)^{1/2} \right],$$

where $A$ is the Richardson constant, $k_B$ is the Boltzmann constant, $q$ is the electron charge, $\Phi$ is the Schottky barrier height (SBH), $K$ is the optical dielectric constant, and $d$ is the sample thickness. Typical fitting results at five different temperatures are shown in Fig. 3(a) (the solid curves of the negative branches). The fitting ranges are uniformly fixed. From the fitting, we estimate the optical dielectric constant $K$. The fitting ranges are uniformly fixed. From the fitting, we estimate the optical dielectric constant $K$.

FIG. 1. (Color online) XRD patterns of (a) BFO/YBCO/STO and (b) YBCO/STO thin films. (c) 3 × 3 μm² topographic AFM image and (d) resistance vs temperature measured on the YBCO/STO thin film. The superconducting transition is indicated by a dashed line in (d).

FIG. 2. (Color online) (a) 3 × 3 μm² topographic AFM image of the BFO thin film grown on YBCO/STO. (b) Corresponding piezoresponse phase image. Yellow (bright) and purple (dark) correspond to the original up and down domains, respectively. Electric field dependence of (c) the spontaneous polarization and (d) the dielectric constant measured at 300 (solid squares) and 77 K (open squares). For comparison, the room temperature $P$-$E$ loop (solid line) of the BFO thin film deposited on a SrRuO$_3$ buffer layer is also shown in (c).

FIG. 3. (Color online) (a) Typical $J$-$E$ characteristics of the Pt/BFO/YBCO heterostructure measured at various temperatures (only 170, 150, 110, 80, and 30 K data are shown for clarity). The solid curves of the negative branches represent the corresponding fitting results using the Schottky-like barrier model. (b) Schottky barrier height $\Phi$ as a function of temperature (open circles), along with the $T$-dependent resistance of YBCO (open squares). The lines are the linear fittings, and the dot line marks the superconducting transition. Inset in (b) is the $T$-dependent refractive index $n$ deduced from fitting. For comparison, $\Phi(T)$ data of the Pt/BFO/SRO junction are also shown (solid circles), and the black line is guide for eyes.
and the barrier height $\Phi$. To reveal the effect of the superconducting transition on the BFO/YBCO interface, we plotted the $T$-dependence of $\Phi$ [Fig. 3(b)]. Interestingly, a clear steplike anomaly of $\Phi(T)$ was observed at $T_c=87$ K. After subtracting the linear background, the deviation of SBH was estimated to be $\sim 19$ meV which is close to the superconducting gap of $\sim 30–60$ meV in YBCO.

Actually, the current Pt-BFO-YBCO structure can be modeled as two Schottky-like diodes with a back-to-back configuration, which would contribute to the transport behavior simultaneously. To exclude the possibility that the observed steplike anomaly of $\Phi(T)$ might originate from the Pt/BFO interface, we also carried out similar measurements on the Pt/BFO/SRO junction, and the absence of the $\Phi(T)$ anomaly in that case as shown in Fig. 3(b) further confirms that the anomaly in the Pt/BFO/YBCO case originates from the superconducting transition of YBCO.

The optical refractive index $n$ can be deduced from the optical dielectric constant $K$ through the relation of $n=\sqrt{K}$.27 Its comparison with the ideal value of about 2.5–3.1 can be used to evaluate the validity of fitting.28–30

The $T$-dependence of $n$ is shown in the inset of Fig. 3(b). Upon cooling to 65 K, $n$ increases within the range of 1.73–3.21. This is close to the expected values, indicating that the Schottky emission dictates the conduction in the BFO/YBCO heterostructures at $T=65$ K further cooling causes a rapid increase of $n$, becoming much larger than the ideal value, which suggests that the Schottky emission plays a less important role at the low temperatures.

In conclusion, high quality $c$-axis oriented epitaxial BFO/YBCO thin film heterostructures were fabricated on SrTiO$_3$ (100) substrate and shown to retain ferroelectricity and superconductivity. The transport behaviors of the BFO/YBCO interface measured at different temperatures can be well described using the Schottky-like barrier model. Furthermore, a steplike anomaly was observed in the temperature-dependent barrier height data, which are associated with the evolution of the superconducting gap in YBCO. These results may encourage future studies on other multiferroic/superconductor heterostructures to explore the interactions across the interfaces and to construct advanced devices with tunable functionalities.

This work was supported by the Singapore National Research Foundation and the Ministry of Education of Singapore (Grant Nos. AcRF RG30/06, ARC 23/08, and ARC 16/08). J.-M. Liu was supported by NSFC (Grant Nos. 50832002 and 10874058).

31W. Schottky, Naturwiss. 26, 843 (1938).